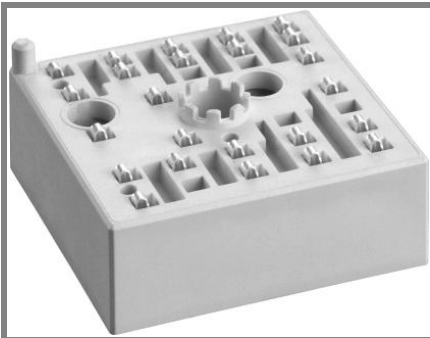


SKiiP 13AC12T4V1



MiniSKiiP®1

3-phase bridge inverter

SKiiP 13AC12T4V1

Features

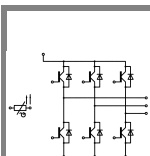
- Trench 4 IGBT's
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

- Inverter up to 14 kVA
- Typical motor power 7,5 kW

Remarks

- V_{CEsat} , V_F = chip level value
- Case temp. limited to $T_C = 125^\circ\text{C}$ max. (for baseplateless modules $T_C = T_S$)
- product rel. results valid for $T_j \leq 150$ (recomm. $T_{op} = -40 \dots +150^\circ\text{C}$)

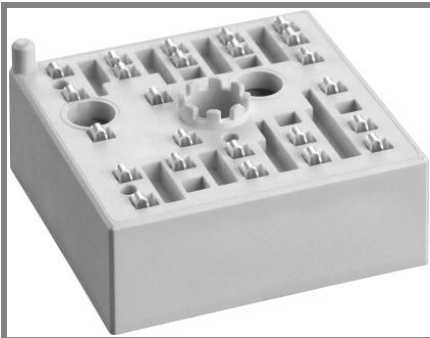


AC

Absolute Maximum Ratings		$T_C = 25^\circ\text{C}$, unless otherwise specified		
Symbol	Conditions	Values		Units
IGBT				
V_{CES}	$T_j = 25^\circ\text{C}$	1200		V
I_C	$T_j = 175^\circ\text{C}$	$T_C = 25^\circ\text{C}$	41	A
		$T_C = 70^\circ\text{C}$	34	A
I_{CRM}	$I_{CRM} = 3 \times I_{Cnom}$	75		A
V_{GES}		±20		V
t_{psc}	$V_{CC} = 800\text{ V}; V_{GE} \leq 15\text{ V}; T_j = 150^\circ\text{C}$ $V_{CES} < 1200\text{ V}$	10		µs
Inverse Diode				
I_F	$T_j = 175^\circ\text{C}$	$T_C = 25^\circ\text{C}$	30	A
		$T_C = 70^\circ\text{C}$	26	A
I_{FRM}	$I_{CRM} = 3 \times I_{Cnom}$	75		A
I_{FSM}	$t_p = 10\text{ ms}; \text{sin.}$	$T_j = 150^\circ\text{C}$	100	A
Module				
$I_{t(RMS)}$		40		A
T_{vj}		-40...+175		°C
T_{stg}		-40...+125		°C
V_{isol}	AC, 1 min.	2500		V

Characteristics		$T_C = 25^\circ\text{C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 1\text{ mA}$	5	5,8	6,5	V
I_{CES}	$V_{GE} = V, V_{CE} = V_{CES}$				$T_j = ^\circ\text{C}$ mA
V_{CE0}		$T_j = 25^\circ\text{C}$	0,8	0,9	V
		$T_j = 150^\circ\text{C}$	0,7	0,8	V
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25^\circ\text{C}$	42	46	mΩ
		$T_j = 150^\circ\text{C}$	62	66	mΩ
$V_{CE(sat)}$	$I_{Cnom} = 25\text{ A}, V_{GE} = 15\text{ V}$	$T_j = 25^\circ\text{C}_{chiplev.}$	1,85	2,05	V
		$T_j = 150^\circ\text{C}_{chiplev.}$	2,25	2,45	V
C_{ies}	$V_{CE} = 25, V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	1,43		nF
C_{oes}			0,12		nF
C_{res}			0,09		nF
Q_G	$V_{GE} = -8 \dots +15\text{ V}$	140		nC	
R_{Gint}	$T_j = 25^\circ\text{C}$	0		Ω	
$t_{d(on)}$	$R_{Gon} = 39\ \Omega$ $di/dt = 465\text{ A}/\mu\text{s}$	$V_{CC} = 600\text{ V}$ $I_C = 25\text{ A}$	44		ns
t_r			46		ns
E_{on}			3,7		mJ
$t_{d(off)}$	$R_{Goff} = 39\ \Omega$ $di/dt = 350\text{ A}/\mu\text{s}$	$T_j = 150^\circ\text{C}$ $V_{GE} = \pm 15\text{ V}$	330		ns
t_f			62		ns
E_{off}			2,4		mJ
$R_{th(j-s)}$	per IGBT	1		K/W	

SKiiP 13AC12T4V1



MiniSKiiP®1

3-phase bridge inverter

SKiiP 13AC12T4V1

Features

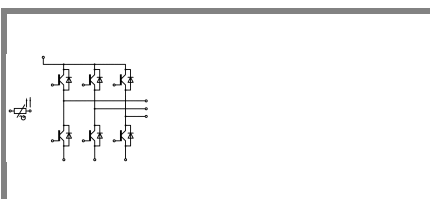
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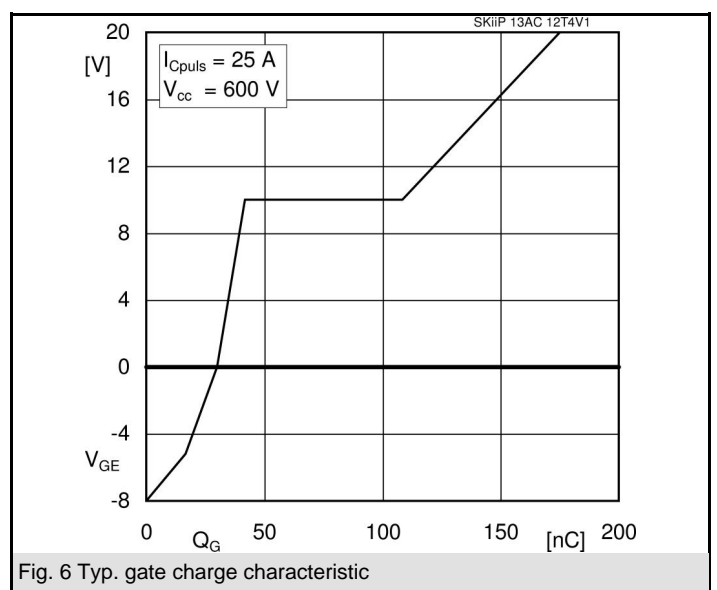
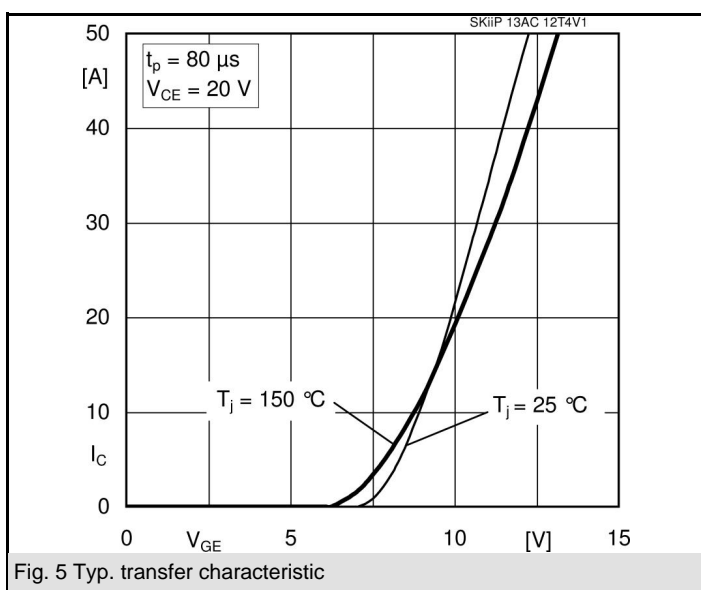
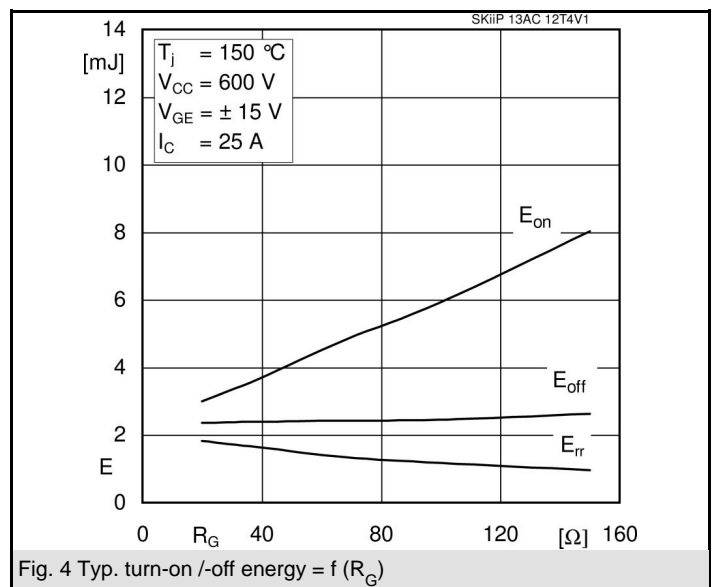
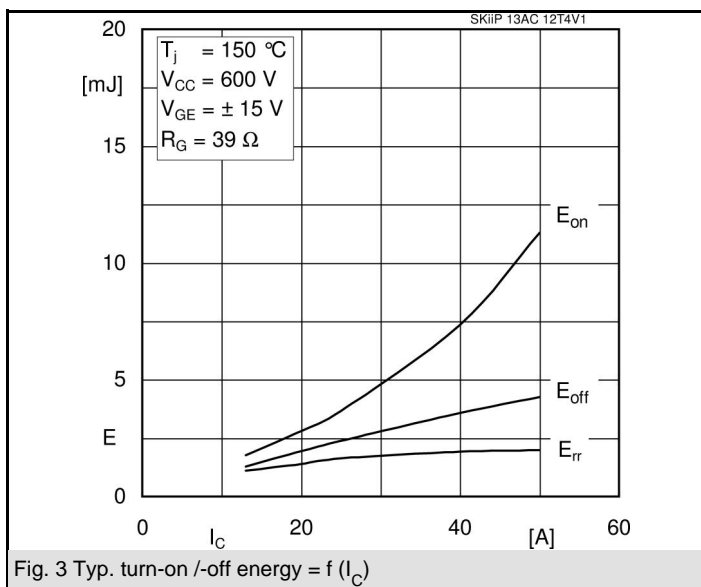
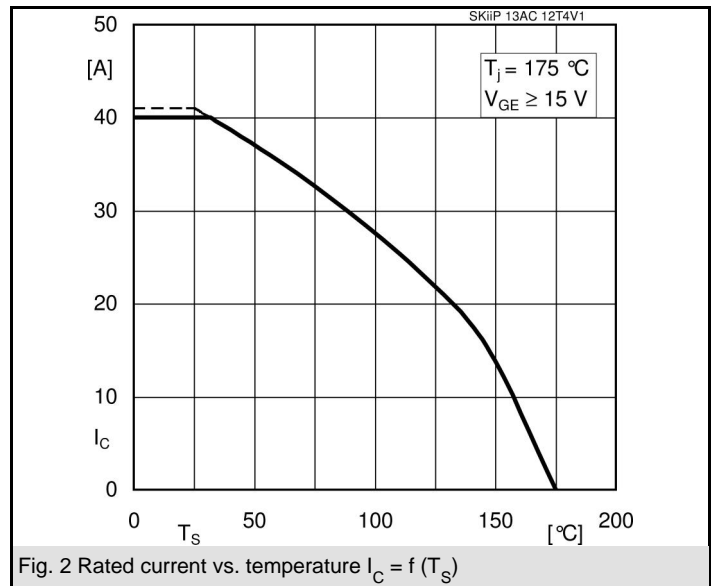
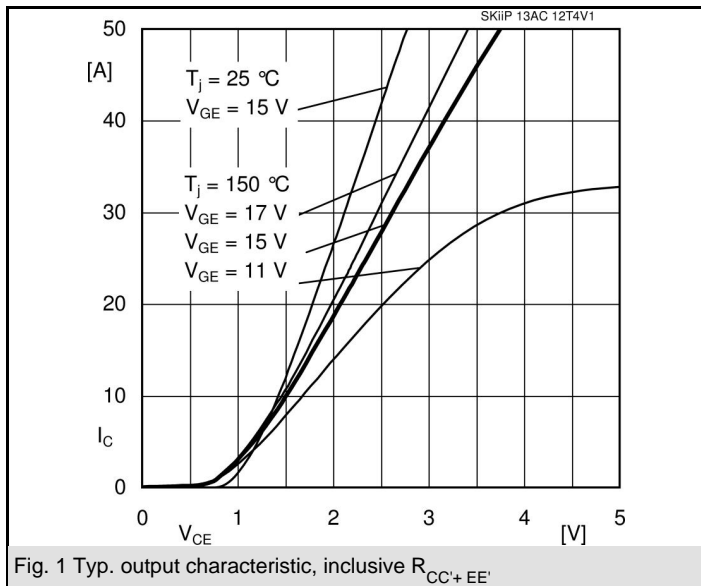


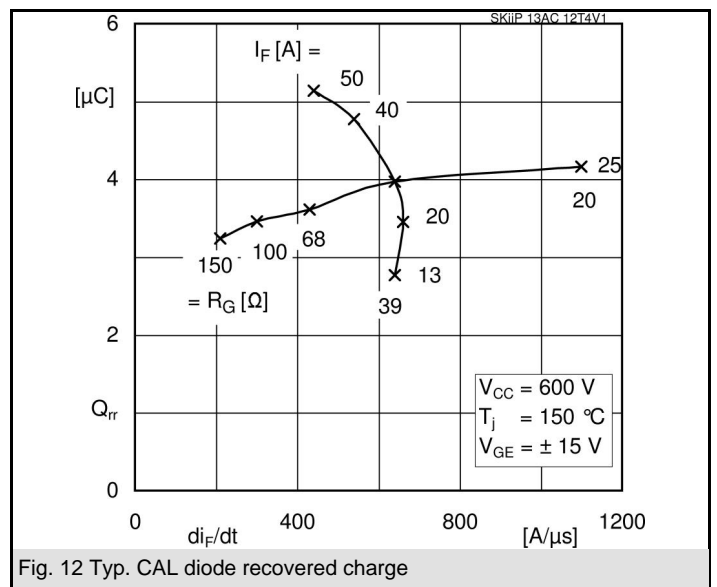
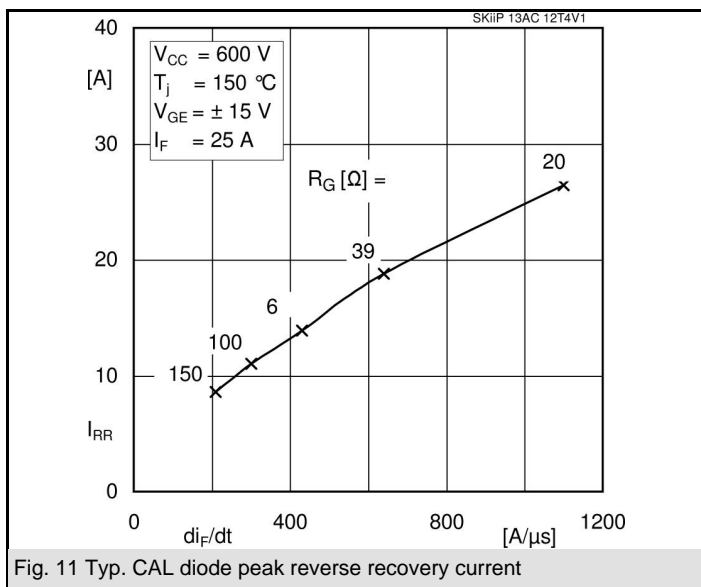
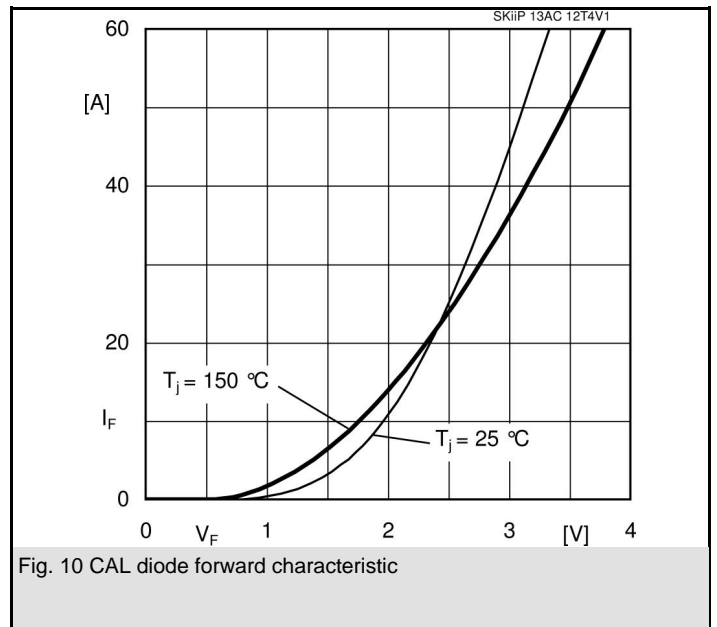
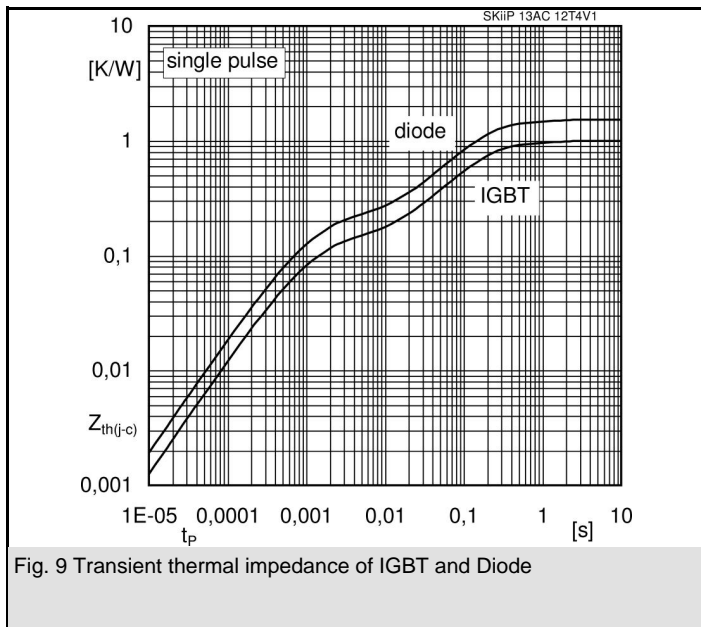
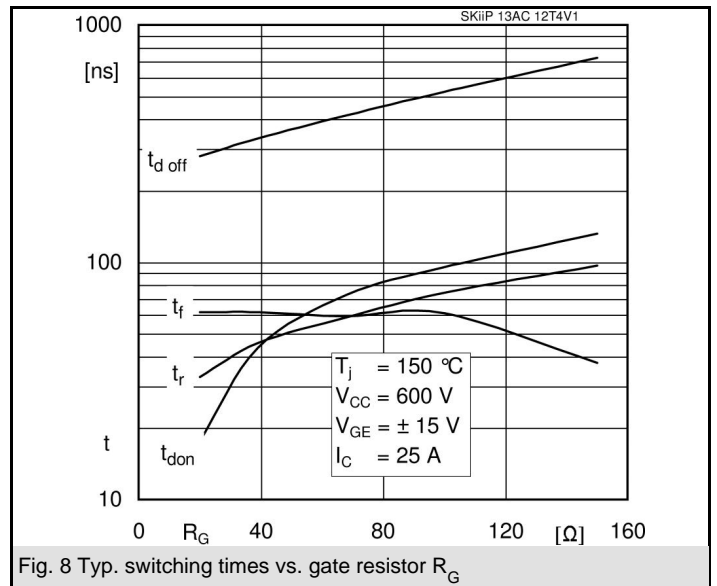
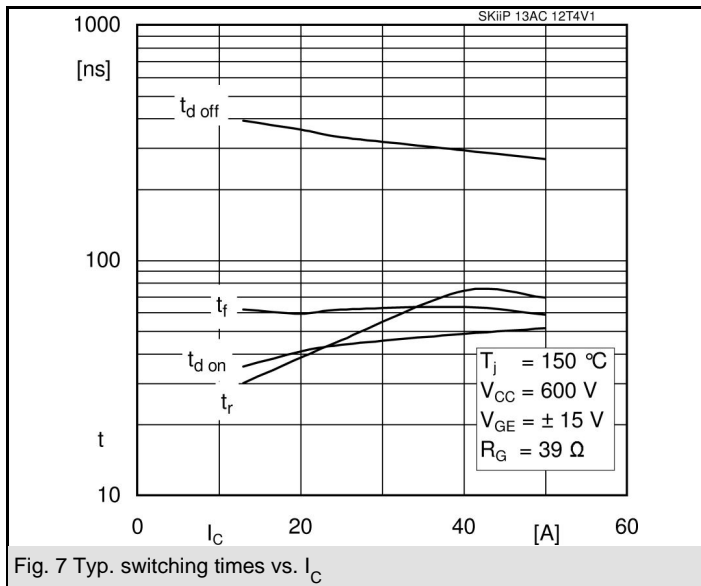
AC

Characteristics				min.	typ.	max.	Units
Symbol	Conditions						
Inverse Diode							
$V_F = V_{EC}$	$I_{Fnom} = 25 \text{ A}; V_{GE} = 0 \text{ V}$	$T_j = 25^\circ\text{C}_{\text{chiplev.}}$		2,4	2,75		V
		$T_j = 150^\circ\text{C}_{\text{chiplev.}}$		2,45	2,8		V
V_{F0}		$T_j = 25^\circ\text{C}$		1,3	1,5		V
		$T_j = 150^\circ\text{C}$		0,9	1,1		V
r_F		$T_j = 25^\circ\text{C}$		44	50		mΩ
		$T_j = 150^\circ\text{C}$		62	68		mΩ
I_{RRM}	$I_F = 25 \text{ A}$	$T_j = 150^\circ\text{C}$		19			A
Q_{rr}	$di/dt = 640 \text{ A}/\mu\text{s}$			4			μC
E_{rr}	$V_{GE} = \pm 15 \text{ V}$			1,64			mJ
$R_{th(j-s)}$	per diode			1,52			K/W
M_s	to heat sink			2	2,5		Nm
w				35			g
Temperature sensor							
R_{ts}	3%, $T_r = 25^\circ\text{C}$			1000			Ω
R_{ts}	3%, $T_r = 100^\circ\text{C}$			1670			Ω

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.



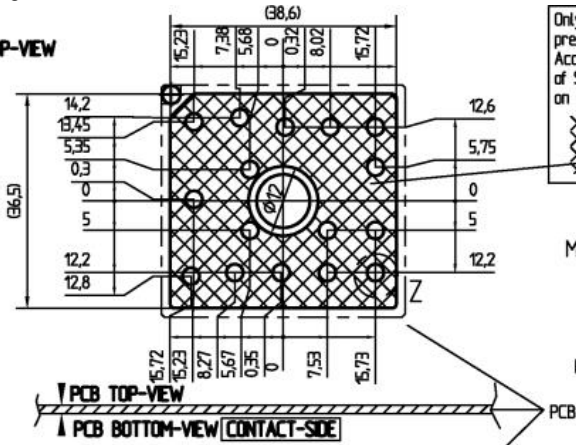


SKiiP 13AC12T4V1

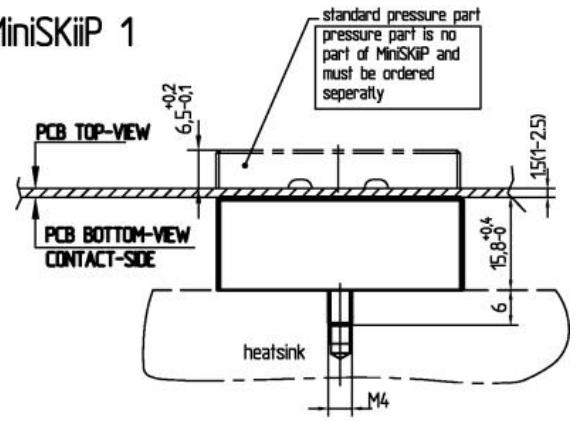
UL recognized file

no. E 63 532

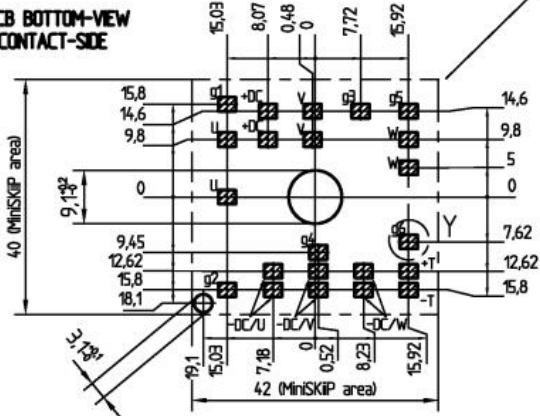
PCB PCB TOP-VIEW



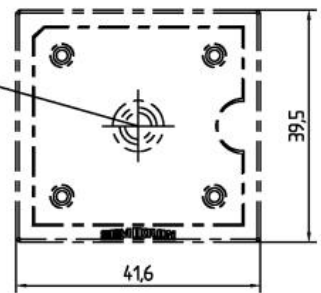
MiniSKiiP 1



PCB BOTTOM-VIEW CONTACT-SIDE

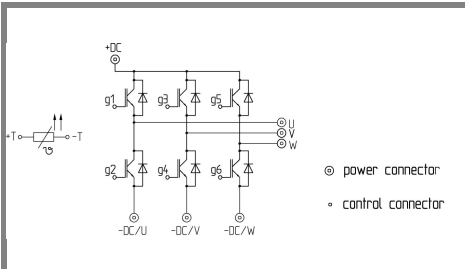


For mounting please follow the assembly instruction



measure: mm
tolerance: ISO 2768-f

case



pinout